

24

Slwave 5.0 PI Advisor for Optimized DDR3 Memory Design

Presented by Sergey Polstyanko, Ph.D Senior R&D Manager

© 2010 ANSYS, Inc. All rights reserved.



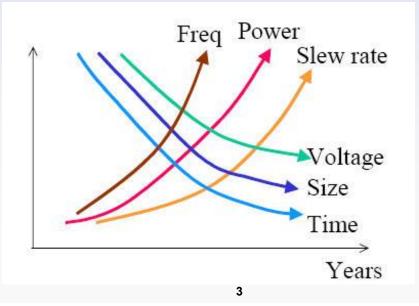


- Design Overview and Challenges
- How to define Target impedance ?
- PI Advisor
- Summary

Design Challenges



- New deep sub-micron technologies
 - Increased device speeds
 - Lower power supply voltages
- Device miniaturization
 - Decreasing design cycles
- Delta-I noise on whole PDS system



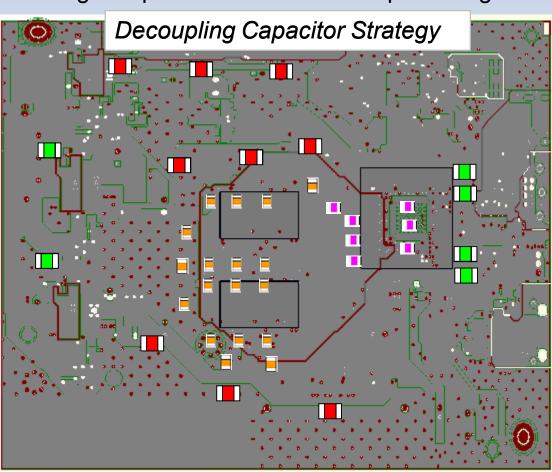
A Typical Scenario



- *Customer X* has a PCB with possible SI/PI related issues
- Management is asking for quick fix and cost reduction
- The Challenge: How to achieve target impedances without compromising SI/PI performance?



High Volume Production



Power Integrity Design



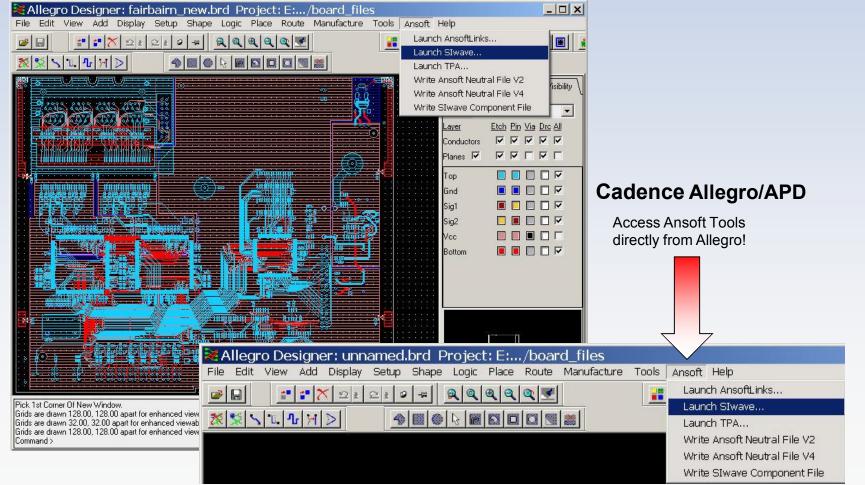
PCB Geometry present

- A functional design, with all decoupling capacitors already placed on PCB
- PI Engineer may want to:
 - Increase capacitor count in order to make design more robust (i.e. overclocking, etc.)
 - Reduce the capacitor count
 - Reduce number of different capacitor types used
 - Redesign using lower cost capacitors
 - Chose appropriate capacitor location

Layout Import and Translation



- Direct access to Ansoft tools from Cadence environment
 - Allegro layout is directly translated and imported in Slwave
 - Component file is also imported



ECAD Databases Supported

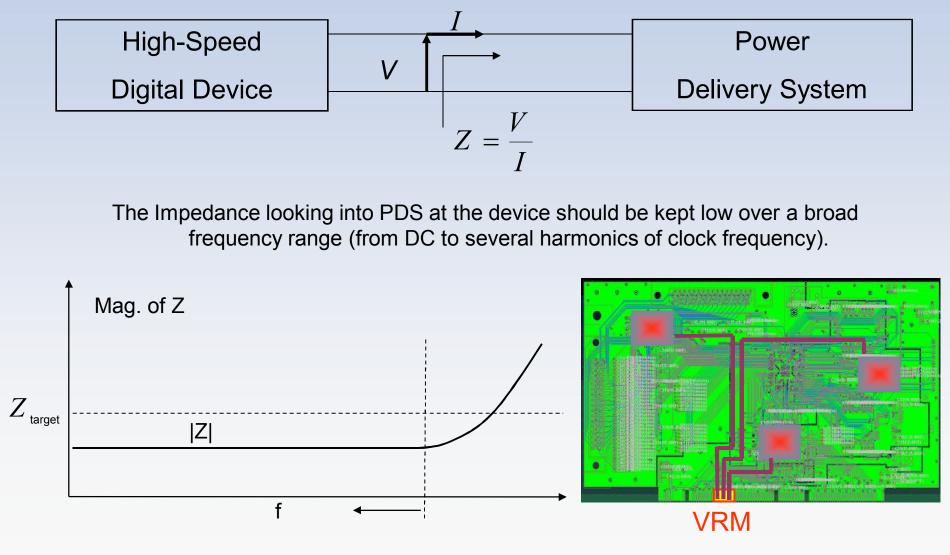


- 1. Cadence Allegro and APD
- 15.0, 15.1, 15.2, 15.5.x, 15.7, 16.0, 16.1, 16.2, and 16.3
- 2. Cadence SiP Digital/RF
- 15.7, 16.0, 16.1, 16.2, and 16.3
- 3. Mentor BoardStation 8.x
- 4. Mentor BoardStation XE/RE v2007.1 and v2007.2
- 5. Mentor Expedition v2004, v2005, v2007.1, v2007.2 and v2007.3
- 6. Mentor PADS (PowerPCB) v5.2a, v2005 (2007 with 2005 export format)
- 7. Synopsys Encore ICPD 2001.x, 2002.x, 2003.x, 2004.x and 2005.x
- 8. Sigrity UPD 9.0 and low
- 9. Zuken CR5000 ⁴
- **10.** Altium Designer

- 9.0 and lower
- 10.x and lower
 - Summer 2010 Beta2 or later

PI Design Goal : Target Impedance of PDS





© 2010 ANSYS, Inc. All rights reserved.

Target Impedance Trends



$$Z_{\text{Target}} = \frac{(Power_Supply_Voltage) \times (Allowed_Ripple)}{Current}$$

$$Z_{\text{Target}(2.5v)} = \frac{(2.5V) \times (5\%)}{40.3A} = 3.1m\Omega$$

*Target Impedance is falling ~ 1.6x, every 3 years

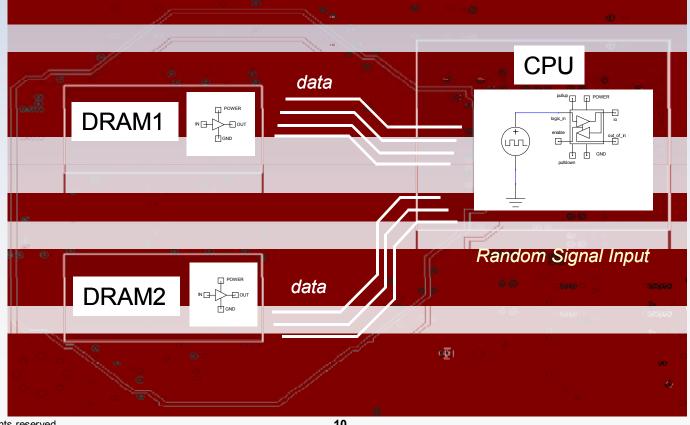
Year of first production	1997	1999	2002	2005	2008
Chip technology	0.25um	0.18um	0.13um	0.10um	0.07um
Across Chip Frequency (MHz)	450	600	800	1000	1100
Max. Chip Power (W)	100	120	140	160	180
Max current (A)	40.3	66.7	93.3	133.3	180.0
Power Supply (V)	2.5	1.8	1.5	1.2	0.9
Target Impedance $(m\Omega)$	3.1	1.3	0.8	0.45	0.25

*Source: International Technology Roadmap for Semiconductors

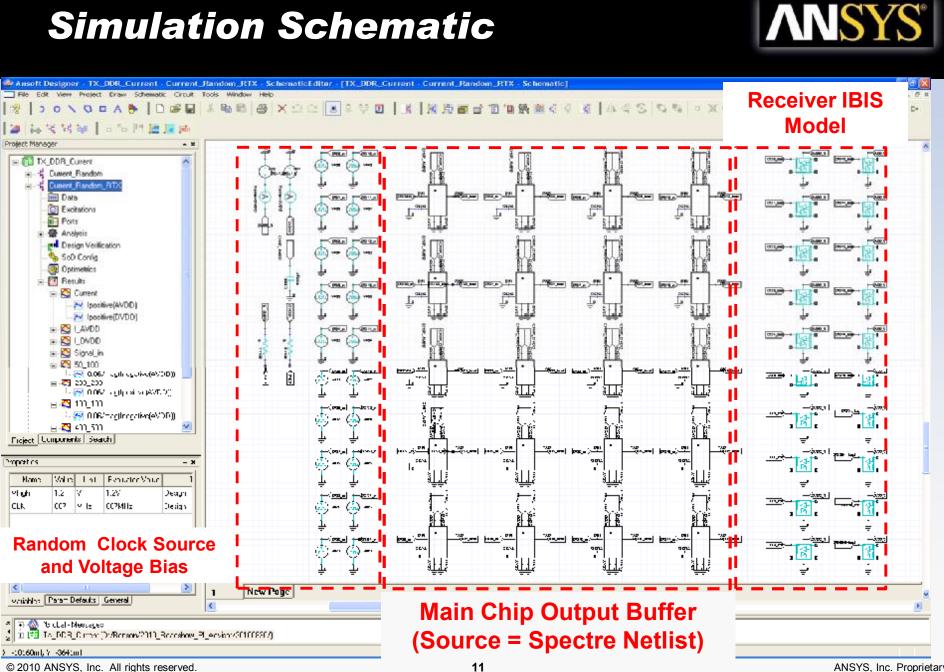
Define Target Impedance



- **Target Impedance**
 - Get TX/Rx models for DRAM and CPU modules •
 - Use Random Signal Input from CPU
 - Get time/frequency domain current profile



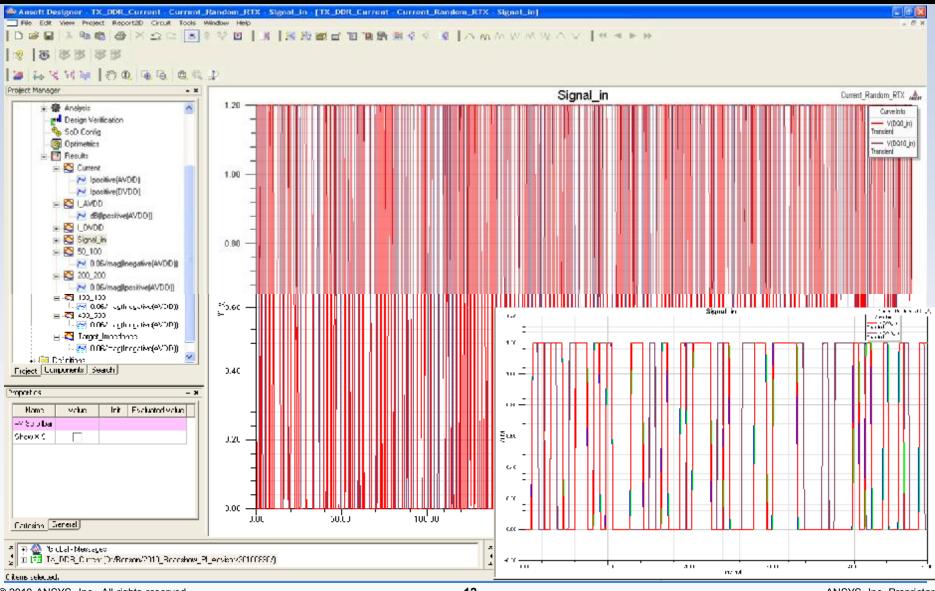
© 2010 ANSYS, Inc. All rights reserved.



Simulation Schematic

Signal Input – Random Clock

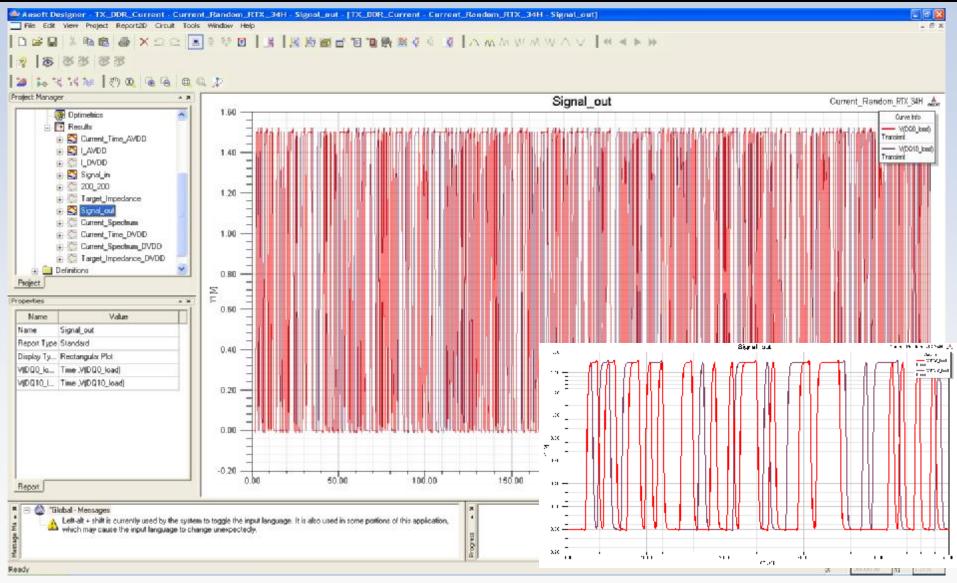




© 2010 ANSYS, Inc. All rights reserved.

Signal Output

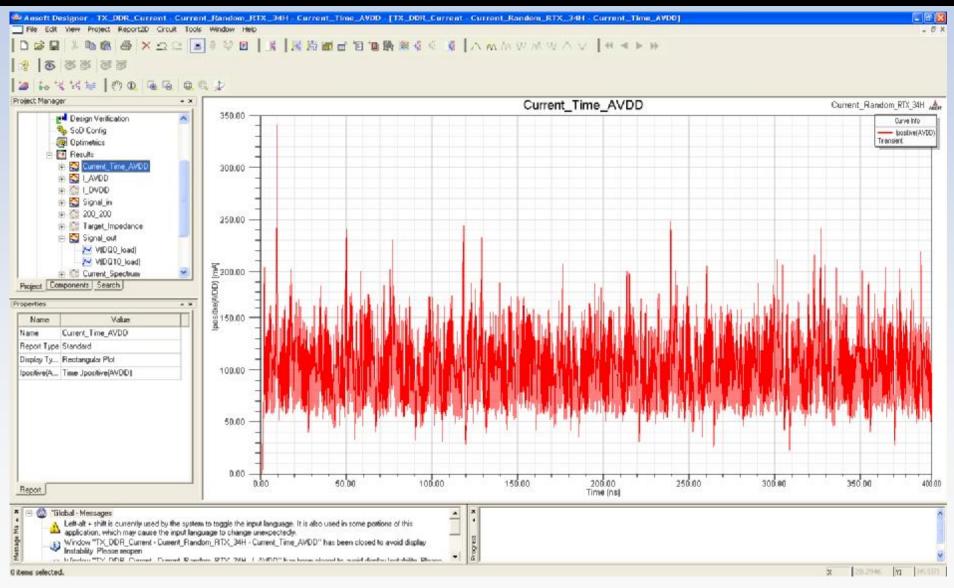




© 2010 ANSYS, Inc. All rights reserved.

Simulation Results – Time domain Current Profile

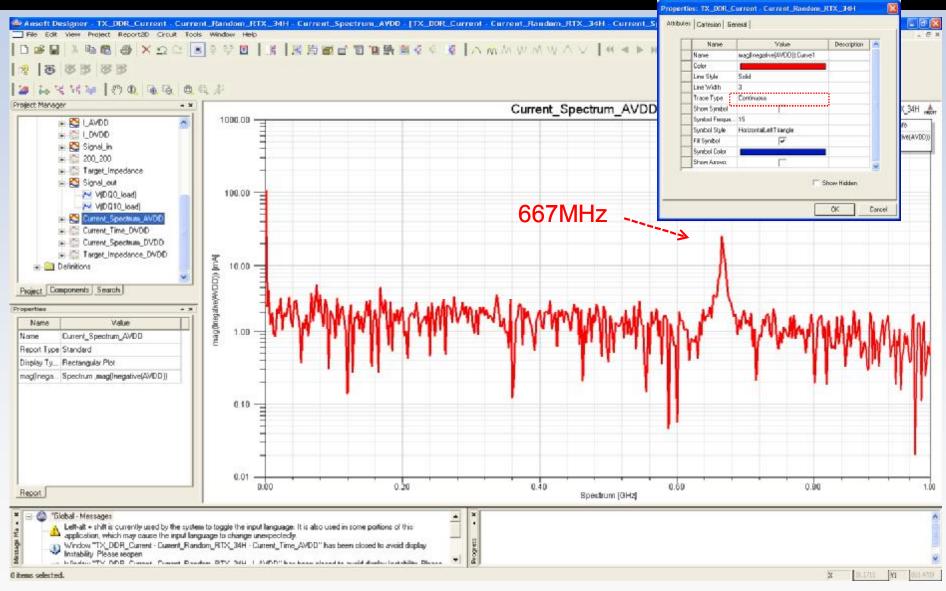


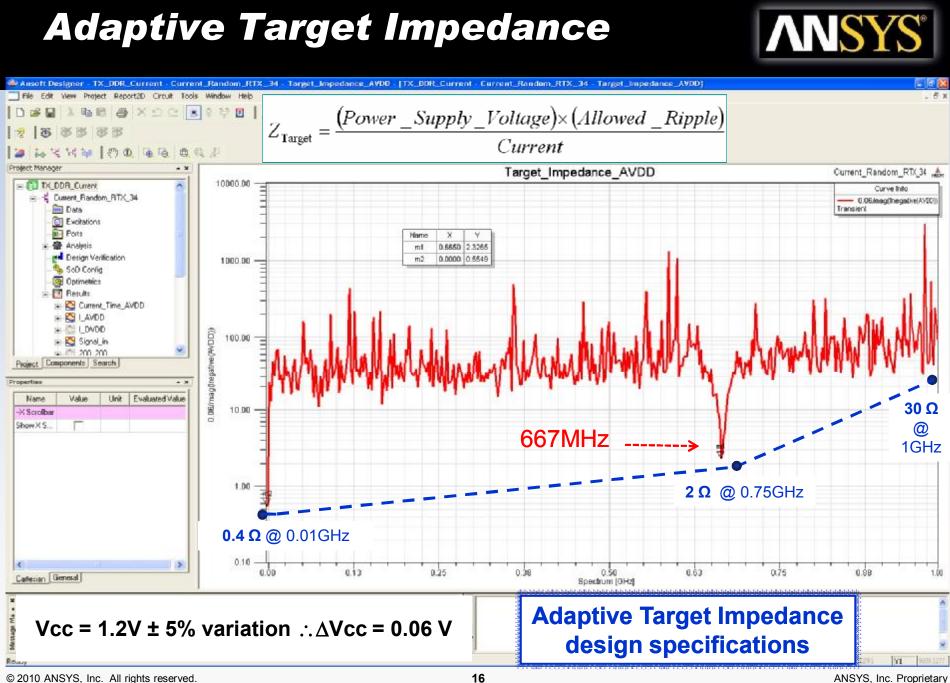


© 2010 ANSYS, Inc. All rights reserved.

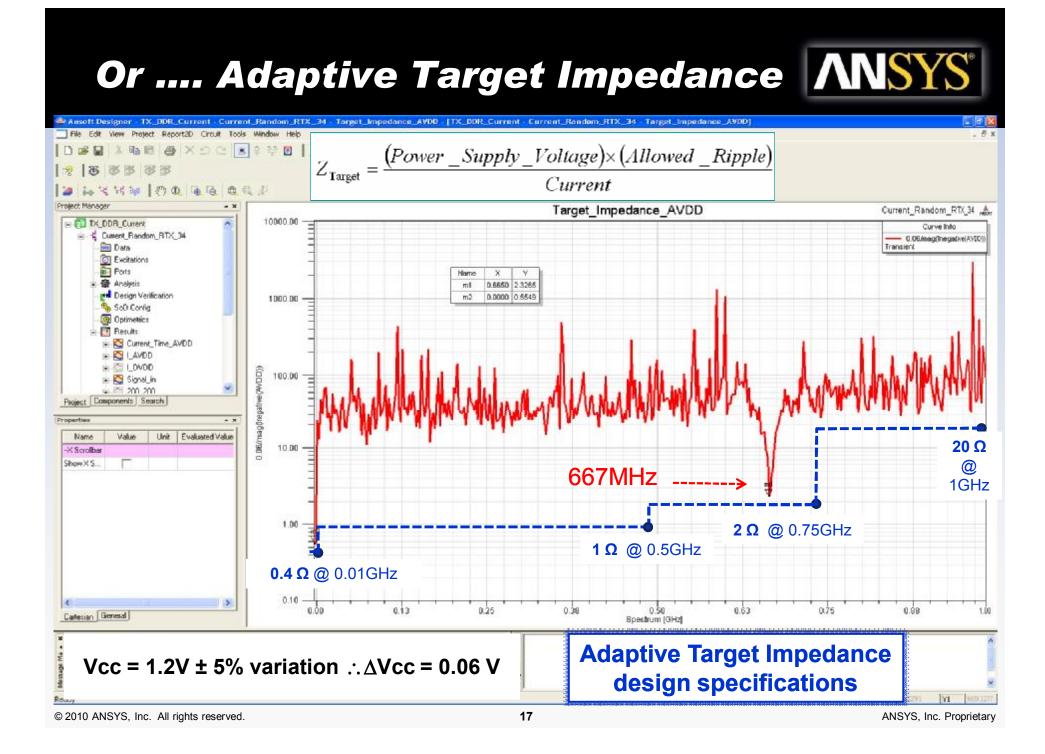
Current Spectrum output Trace type - Continuous







© 2010 ANSYS, Inc. All rights reserved.

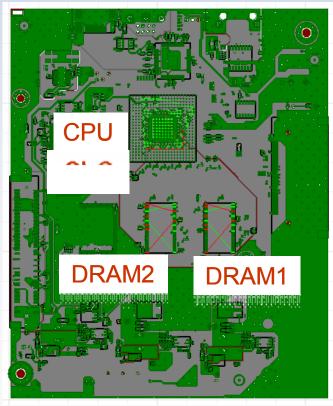


PCB Layer Structure



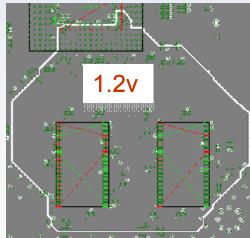
- High-speed signals are routed between CPU and DRAM
 - Minimize noise voltage distribution on the VCC/GND plane pair
 - Design of this Power/Ground plane is the most important aspect of design
 - Low power bus impedance over frequency

3 ports defined



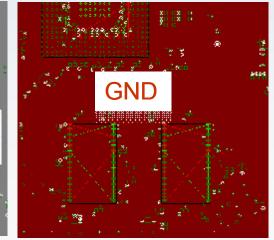
Layers	▼ ‡
	¥
O SURFACE	
_ vcc	
○ GND	~
◯ BASE	~

Power Plane





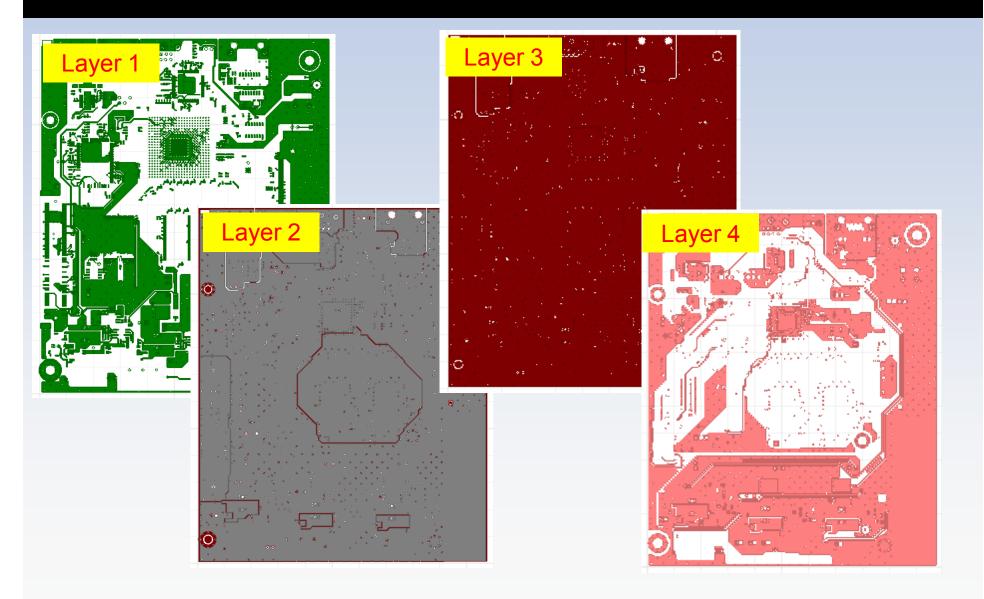
Ground Plane



© 2010 ANSYS, Inc. All rights reserved.

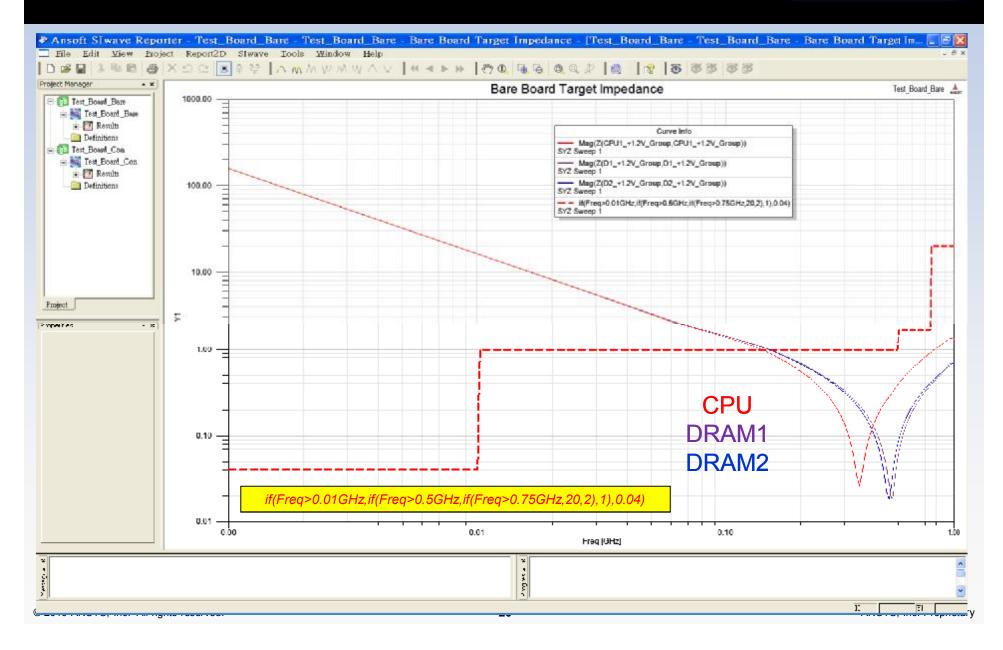
PCB Layer Structure





Bare Board Impedance





Original Design All 1.2V to GND 36 Capacitors ON

Circuit Element Properties

Original Design -Total 36 Caps

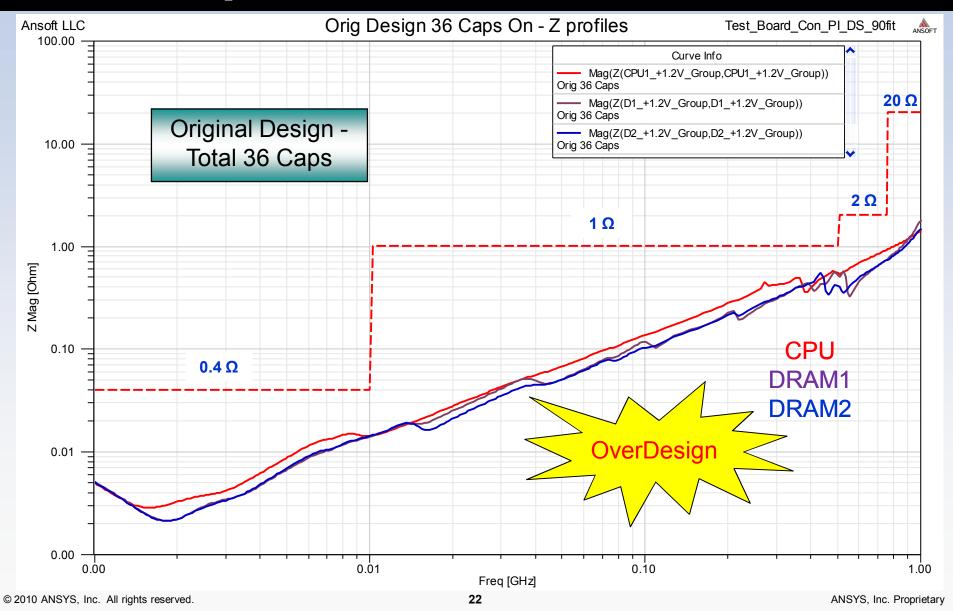
Types of Capacitors GRM21BC70G106ME45 GRM21BF51A225ZA01 GRM21BF51H224ZA01 GRM21BR71E104KA01 GRM216F51H103ZA01 GRM216F51H224ZA01 GRM1885C1H201JA01 GRM1885C1H820JA01

	Active:	15:51	Part Number	RefDes	Capacitance (F)	Parasitic L (H)	Parasitic R (ohms)	Positive "	Negative -
	Yes	×	GRM1885C1H820JA01	C1	8.2E-11	7.00689E-10	0.155633	+1.2V	GND
	Yes	x	GRM188R71H221KA01	C2	2.2E-10	5.22762E-10	0.964207	+1.2V	GND
	Yes	×	GRM1885C1H201JA01	C3	2E-10	7.63124E-10	0.121881	+1.2V	GND
	Yes	×	GRM218F51A225ZA01	C4	2.2E-06	3.4867E-10	0.00433996	+1.2V	GND
	Yes	×	GRM188F51C225ZA01	C5	2.2E-06	4.00639E-10	0.00796341	+1.2V	GIND
	Yes	×	GRM218F51A225ZA01	CG	2.2E-06	3.4867E-10	0.00433996	+1.2V	GND
	Yes	×	GRM218F51A225ZA01	C7	2.2E-06	3.4867E-10	0.00433996	+1.2V	GND
	Yes	×	GRM218F51A225ZA01	C8	2.2E-06	3.4867E-10	0.00433996	+1.2V	GND
	Yes	×	GRM218F51A225ZA01	C9	2.2E-06	3.4867E-10	0.00433996	+1.2V	GND
	Yes	×	GRM1885C1H561JA01	C11	5.6E-10	5.8294E-10	0.0910925	GND	+1.2V
	Yes	×	GRM21BR71E104KA01	C12	1E-07	5.00196E-10	0.0194763	GND	+1.2V
	Yes	×	GRM1885C1H820JA01	C13	8.2E-11	7.00689E-10	0.155633	GND	+1.2V
	Yes	×	GRM218F51A225ZA01	C14	2.2E-06	3.4857E-10	0.00433996	+1.2V	GND
	Yes	×	GRM2165C1H202JA01	C15	2E-09	5.60276E-10	0.0666069	+1.2V	GND
	Yes	×	GRM188R60J474KA01	C16	4.7E-07	5.35164E-10	0.00913529	+1.2V	GND
	Yes	×	GRM216F51H102ZA01	C17	1E-09	4.96929E-10	0.293964	+1.2V	GND
	Yes	×	GRM218R71E104KA01	C18	1E-07	5.00196E-10	0.0194763	GND	+1.2V
	Yes	×	GRM1885C1H910UA01	C19	9.1E-11	6.56454E-10	0.143556	GND	+1.2V
	Yes	×	GRM1885C1H101JA01	C20	1E-10	8.22615E-10	0.203464	GND	+1.2V
	Yes	×	GRM21BRE1A475KA73	C21	4.7E-06	2.98349E-10	0.00361006	+1.2V	GND
	Yes	x	GRM216F51H224ZA01	C22	2.2E-07	4.73639E-10	0.0292659	+1.2V	GND
	Yes	×	GRM216F51H224ZA01	C49	2.2E-07	4.73639E-10	0.0292659	+1.2V	GND
	Yes	×	GRM218F51H224ZA01	C51	2.2E-07	5.86749E-10	0.0214453	+1.2V	GND
	Yes	×	GRM216F51A334ZA01	C52	3.3E-07	6.0008E-18	0.0204213	+1.2V	GND
	Yes	×	GRM216F51H103ZA01	C181	1E-08	6.60515E-10	0.0822853	+1.2V	GND
	Yes	×	GRM216F51H103ZA01	C170	1E-08	6.60515E-10	0.0822853	+1.2V	GND
	Yes	×	GRM216F51H103ZA01	C180	1E-08	6.60515E-10	0.0822853	+1.2V	GND
	Yes	×	GRM216F51H103ZA01	C167	1E-08	6.60515E-10	0.0822853	+1.2V	GND
	Yes	×	GRM1885C1H121JA01	C43	1.2E-10	8.07155E-10	0.194061	+1.2V	GIND
	Yes	×	GRM21BF51A225ZA01	C45	2.2E-06	3.4867E-10	0.00433996	+1.2V	GND
	Yes	×	GRM21BR71E104KA01	C46	1E-07	5.00196E-10	0.0194763	+1.2V	GND
	Yes	×	GRM1885C1H820JA01	C47	8.2E-11	7.00689E-10	0.155633	+1.2V	GND
	Yes	×	GRM1885C1H820JA01	C48	8.2E-11	7.00689E-10	0.155633	+1.2V	GND
	Yes	×	GRM2165C1H302JA01	C312	3E-09	5.98851E-10	0.0441419	GND	+1.2V
	Yes	×	GRM218C70G106ME45	C316	1E-06	2.44675E-10	0.00293246	GND	+1.2V
	Yes	×	GRM188R71H271KA01	C317	2.7E-10	5.51632E-10	0.813567	GND	+1.2V
	No	×	GRM21BR71E104KA01	C26	1E-07	5.00196E-10	0.0194763	GND	AVDD
	Na	×	GRM21BR71E104KA01	C27	1E-07	5 00196E-10	0.0194763	PLLVCC	GND
	No	×	GRM218R71E104KA01	C28	1E-07	5.00196E-10	0.0194763	PLLVCC	GND
	No	×	GRM218R71E104KA01	C29	1E-07	5 00196E-10	0.0194763	GNID	+3.3V
6	Propertie	м	Modify Layers	Delete		Fit Selection	Activate		Deactivate

×

Original Design All 36 Capacitors Enabled





Launch Slwave PI Advisor...

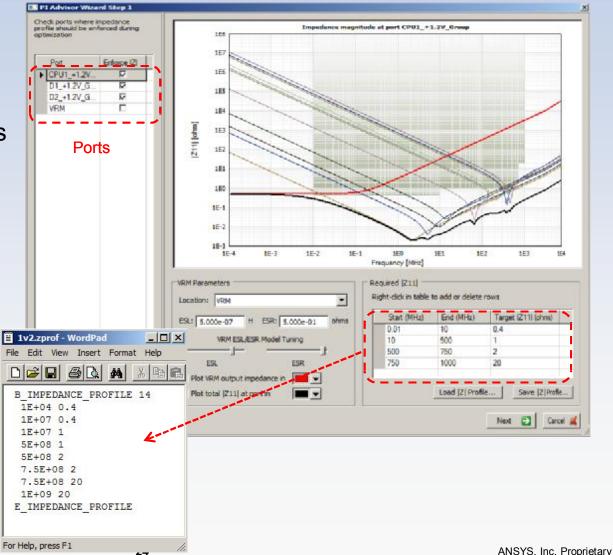


M Test_Board_Con_DS.siw - SIwave	
Eile Edit View Draw Circuit Elements Tools	Simulation Results Help
: 🗅 😂 🔙 🔏 🗈 🖎 🔶 🔊 🗠 👞 🛣	Options
🗄 🔾 🖓 🛄 🗽 Add (No Merge) 🕌 🔛	Compute Resonant Modes
: 🗶 🗶 🗶 🔠 🇱 🗱 🔀 💫 🏬 ; x: 2461.45	Compute <u>Frequency</u> Sweep
Single Ended Nets 🛛 👻 📮 🗙 Differential Ne	Compute S-, Y-, Z-parameters
Regular Exp:	Compute Far Field
□+1.2V	Compute Near Field
□ +1.8V □ +1.8V BST	Compute DC Current/Voltage
□+1.8V_BSTRC □+1.8V_FB	SIwizard (Designer/Nexxim Link)
□ +1.8V_HG □ +1.8V HGR	PI Advisor

Step 1 : Define Ports and Target Impedance Profile

PI Advisor

- Select Reference Port Locations
- Set the VRM Parameters including ESL & ESR
- Define Impedance Mask



ANSYS[®]

Step 2 : Select Capacitors for Automated Optimization

CPU1_+1.2V_Group D1_+1.2V_Group D2_+1.2V_Group

PI Advisor

- Select Capacitor set that needs to be optimized
- All 36 caps selected

Part Name	Ref. Des.	Value (F)	Optimize	
GRM21BC70G106ME45	C316	1E-05		
GRM21BF51A225ZA01	C4	2.2E-06		
GRM21BF51A225ZA01	C6	2.2E-06		
GRM21BF51A225ZA01	C7	2.2E-06		
GRM21BF51A225ZA01	C8	2.2E-06		
GRM21BF51A225ZA01	C9	2.2E-06		
GRM21BF51A225ZA01	C14	2.2E-06		
GRM21BF51A225ZA01	C45	2.2E-06		
GRM21BF51H224ZA01	C51	2.2E-07		
GRM21BR61A475KA73	C21	4.7E-06		
GRM21BR71E104KA01	C12	1E-07		
GRM21BR71E104KA01	C18	1E-07		
GRM21BR71E104KA01	C46	1E-07		
GRM188F51C225ZA01	C5	2.2E-06	N	
GRM188R60J474KA01	C16	4.7E-07		
GRM188R71H221KA01	C2	2.2E-10		
GRM188R71H271KA01	C317	2.7E-10		
GRM216F51A334ZA01	C52	3.3E-07		
GRM216F51H102ZA01	C17	1E-09	N	
GRM216F51H103ZA01	C167	1E-08		
GRM216F51H103ZA01	C170	1E-08		
GRM216F51H103ZA01	C180	1E-08		
GRM216F51H103ZA01	C181	1E-08	N	
GRM216F51H224ZA01	C49	2.2E-07	2	
GRM216F51H224ZA01	C22	2.2E-07		
GRM1885C1H101JA01	C20	1E-10		
GRM1885C1H121JA01	C43	1.2E-10		
GRM1885C1H201JA01	C3	2E-10	N	
GRM1885C1H561JA01	C11	5.6E-10	A	
GRM1885C1H820JA01	C13	8.2E-11		
GRM1885C1H820JA01	C47	8.2E-11		
GRM1885C1H820JA01	C48	8.2E-11		
GRM1885C1H820JA01	C1	8.2E-11		
GRM1885C1H910JA01	C19	9.1E-11	A	
GRM2165C1H202JA01	C15	2E-09		
GRM2165C1H302JA01	C312	3E-09		
			14 - 1	

ANSYS[®]

Step 3 : Select Candidate Capacitors for Optimization



	Part N	arne .	Ref. Dez.	Vial -
	GR/M2	IBF51A225ZA01	C3	2.2
1	GRM2	18F51H224ZA01	C51	2.1
1	GRM2	18F51H224ZA01	C\$3	2.7
1	GRM2	IBF51H224ZAD1	C2	2.7
1	GRM2	1BR 71E 104KA01	C11	1E-
1		IBR 71E 10-9(A01	C 12	18-
1	100000000	18R71E104KA01	C13	1E-
1		IBR 71E 10 4(A01	C 18	1E-
1		UBR 71E 104KAD1	C 19	1E-
4		18R71E104KA01	C46	1E-
1		IBR71E104(A01	C20	1E-
1		HEFS H103ZAD1	C 180	拒
•	CONTRACTOR OF	16F51H103ZA01	C 170	拒
1		16F51H103ZA01	C 167	1E-
•		16F51H103ZA01	C 182	1E
4		16F51H103ZAD1	C181	15
•		16F51H224ZA01	C49	2.2
1		16F51H224ZA01	C50	2.2
1		06F51H224ZA01	C22	2.7
1		885C1H2013A01	C58	2E-
		885C1H2013A01 885C1H8203A01	C56	25
2		889C1H8200A01	C-48	8.2
		88 9C 1H8203A01	C52	8.7
5		889C1H8200A01	C55	8,2
				*
(*
_	ned Can dor	didate Models	Part Name	
Mur		GRM21	GRM219R71C47	Concernment of the local division of the loc
	ata	GRIMI21	GRM219R71C56	
-	ata	GRIM21	GRM219R71C68	100000
	ata	GRM21	GRM219R71E10	
Aur.	ata	GRM21	GRM219R71E22	WA01
Mur	ata	GRM21	GRM219R71H33	3KA01
Mur	ata	GRIM21	GRM219R71H33	46488
Mur	ata	GRM21	GRM219R71H39	3KA01 -
MUR	ata	GRM21	GRIM2165C 1H10	21401
di.				+
-				- Sector

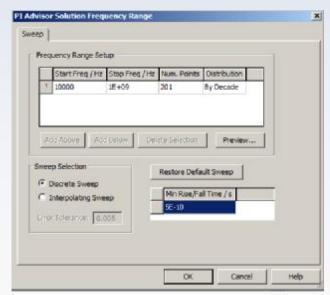


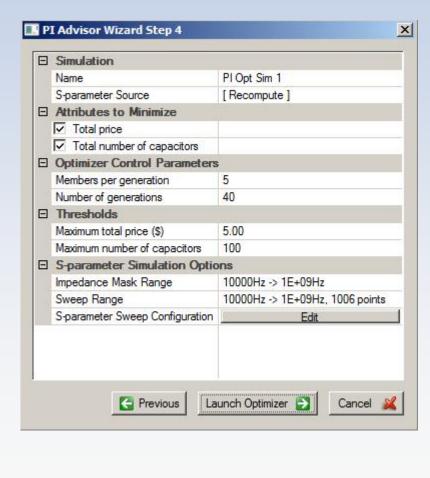
Step 4 : Setup Optimization Criteria

NNSYS[®]

PI Advisor

- Launch PI Advisor Wizard
- Set Optimizer Goal Parameters
- Set Thresholds
 - Total price \$\$\$
 - Total number of capacitors
- Genetic Algorithm is used for optimization
- SYZ sweep





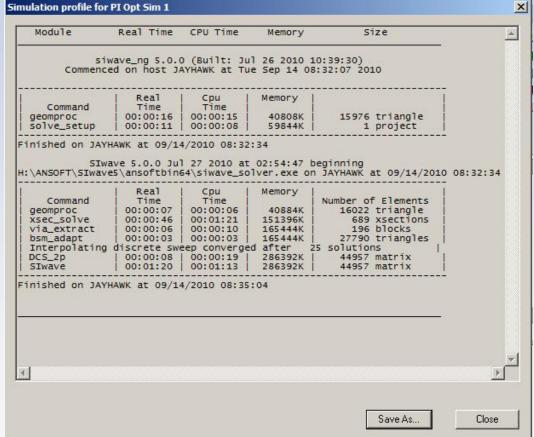
© 2010 ANSYS, Inc. All rights reserved.

Step 5 : Launch Optimizer and Analyze Results

• Time = 2 minutes 56 seconds

• RAM = 286 MB

- Frequency Setup
 - 10KHz < f < 1GHz
 - 201 Points/decade
- Genetic Algorithm Setup
 - Optimized for Impedance
 - Optimized for # of Caps
 - Optimized for Price



PI Advisor – Step 5

PI Advisor Results

- PI Advisor provides multiple different Schemes
- Sort solutions by Price (\$), Num Caps and Goodness of Fit
- You can display Impedance Mask . Etc
- Apply optimized capacitor scheme to the existing design
- Export BOM file back to layout database

isemes.							Inpo	dance at port "CPU1_+1.2	V_Group' for Schee	ne ik
Narec	Goodheas of	Fit Pri	ot 创 Nur	n Caps Cap Types		161				
Schene 8	1	0.1	11 11							
Scheine 7	D. 099039	0.1	18 18							
Scheme 6	D.883764	0.1								
Scheme 5	0.975723	0.1								
Scheme 4	D. \$508.19	.0.1	15 18							
Slicine 3	0.949049	0.1								
Schere 2	0.933661	0.1								
Schene 1	0.431352	-0.1								
Scheine D	0.823017	0.1	15 16	13		160				/
Apply Sch	ene to Design	Cop	ort Schama B	юн						AJ
C		120								All
2 10000	ected for Schem	All Same	19970							101
Capacitor	VALUE \$7	Nendor	Series	Part	Price (8) -		10			
CIZ	(emb/A)		0.222	1. S. P. 1. S. P. 1. S. P.	223	-				
C13	1.92-10	Nurata	CERMIN	GRM 1885C1-13 11A/11	0.01	111(open)			/	1
CI4	(cmpty)					100 t	1		1	V
015	(enpty)					14			/	1
C16 C17	(enoty)	Nurata	GRANIE	GRM 198871-11236A01	222		1		1	
C17 C18	1,35-09	Murata	Legel 18	CHP 189(71-11220/01	0.83		1		1	
C19	(empts) 2.32-06	Muneta	CR9421	GRM218R71C225(AL2	2.22				1	
C19		PLEASE	LH07021	GRP210K7112250A12	0.11			1	N	
C10	(empty)								1	
C21	(cmu/s) 1.3E-08	Munth	GRPI21	GR#2195C1+1231A81	0.01			\ A /	¥	
C41	1.2E-06 1E-06	Munth		GRAD REPORTE TO SEA 12				X M		
C45	General)	ALC: 10.0	ranet/1	2010 2 PM 1 2 10 4 4 12		10.2		VIV		
C45	(emproy)					- 64.6				
547	2.32-07	Manada	1227118	GRM 189871022-90401	2.41					
C18	(cmpor)		1001110	AND REAL PROPERTY.				~		
049	(enpty)									
C\$1	(enp.x) (enp.x)									
CS2	2.76-10	Nurata	CRIMILS	GRM 198871-07 80401	0.01					
	6.85-10	Huneta	GROTLE	GRM 155R71-168 30401						
1457	12-09	Mareta	C#P121	GRM 2 30P5 3H 3022A81						
		Murata	049921	GRN 1/86800239PE19						
C170		1000	ALC: NO.	A STATEMENT OF LIVE		10-7				
C170 C190	2.32.05									
C187 C170 C180 C181 *	2.32405 (rmcv)				L	18-3	18-1	IIID Frequency [*	181	382

© 2010 ANSYS, Inc. All rights reserved.

NNSYS[®]

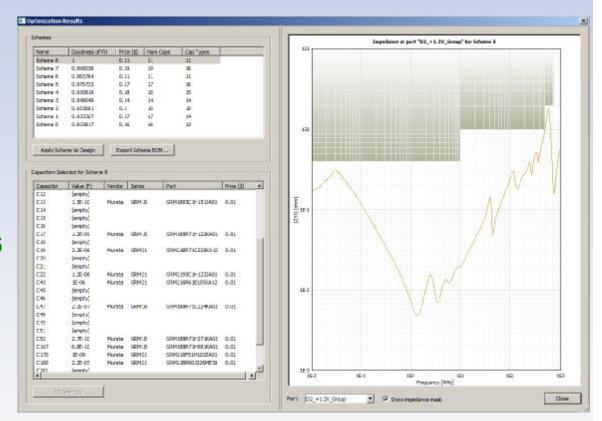
Step 5 : Launch Optimizer and Analyze Results

Original solution

Total # Caps: 36

Optimized Solution

- Total # Caps: from 10 to 19
- 9 Schemes available
- 6 Capacitor Types: 10 to 16



NNSYS°

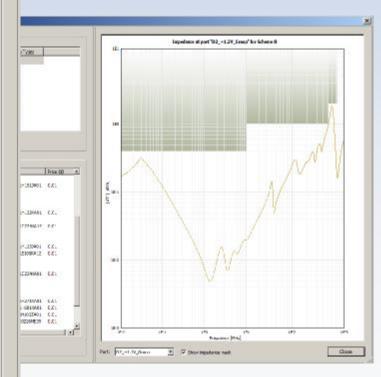
PI Advisor Simulation Results

NNSYS[®]

Scheme 8 Capacitors Selection information

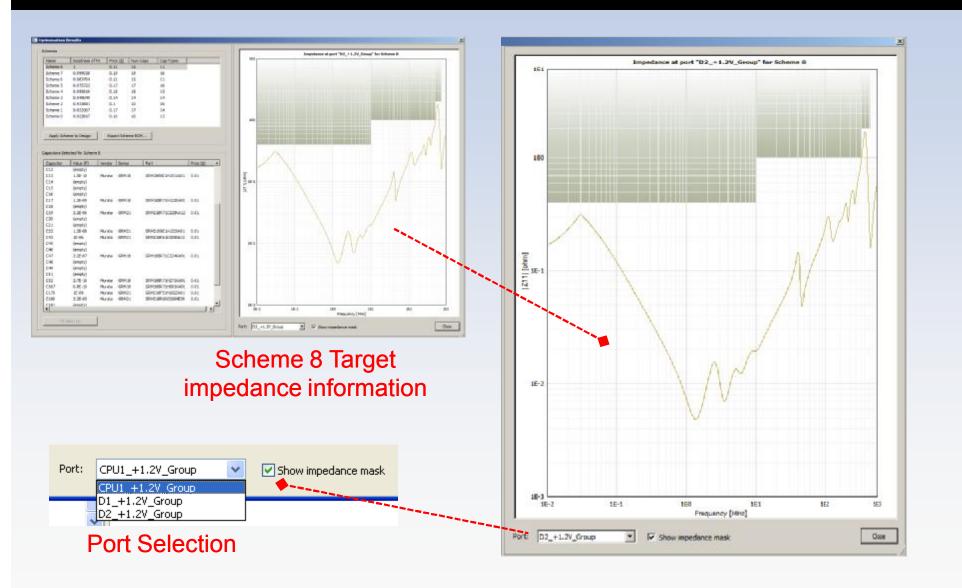
11 capacitors and 11 different types

Capacitor	Value (F)	Vendor	Series	Part	Price (\$)	_
C12	(empty)					
C13	1.5E-10	Murata	GRM18	GRM1885C1H151JA01	0.01	
C14	(empty)					
C15	(empty)					
C16	(empty)					
C17	1.2E-09	Murata	GRM18	GRM188R71H122KA01	0.01	
C18	(empty)					
C19	2.2E-06	Murata	GRM21	GRM21BR71C225KA12	0.01	
C20	(empty)					
C21	(empty)					
C22	1.2E-08	Murata	GRM21	GRM2195C1H123JA01	0.01	
C43	1E-06	Murata	GRM21	GRM216R61E105KA12	0.01	
C45	(empty)					
C46	(empty)					
C47	2.2E-07	Murata	GRM18	GRM188R71C224KA01	0.01	
C48	(empty)					
C49	(empty)					
C51	(empty)					
C52	2.7E-10	Murata	GRM18	GRM188R71H271KA01	0.01	
C167	6.8E-10	Murata	GRM18	GRM188R71H681KA01	0.01	
C170	1E-09	Murata	GRM21	GRM216F51H102ZA01	0.01	
C180	2.2E-05	Murata	GRM21	GRM21BR60J226ME39	0.01	
C181	(emotv)					_
•						F
Fit S	Selection	1				



PI Advisor Simulation Results





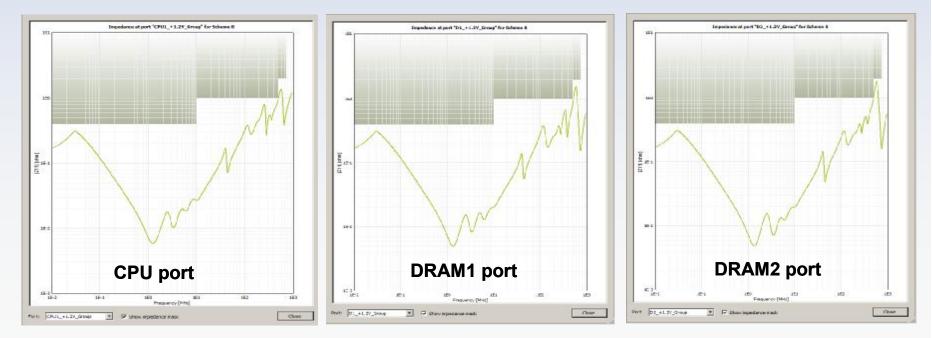
© 2010 ANSYS, Inc. All rights reserved.

Scheme 8 Results – All three ports ANSYS

Optimization Results

lame	Goodness of Fit	Price (\$)	Num Caps	Cap Types
cheme 8	1	0.11	11	11
cheme 7	0.999038	0.19	19	16
cheme 6	0.983764	0.11	11	11
cheme 5	0.975723	0.17	17	16
cheme 4	0.950819	0.18	18	15
cheme 3	0.949049	0.14	14	14
cheme 2	0.933681	0.1	10	10
cheme 1	0.933367	0.17	17	14
cheme 0	0.923817	0.16	16	13
cheme 0	0.923817	0.16	16	13



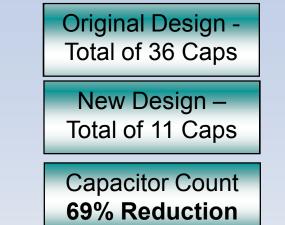


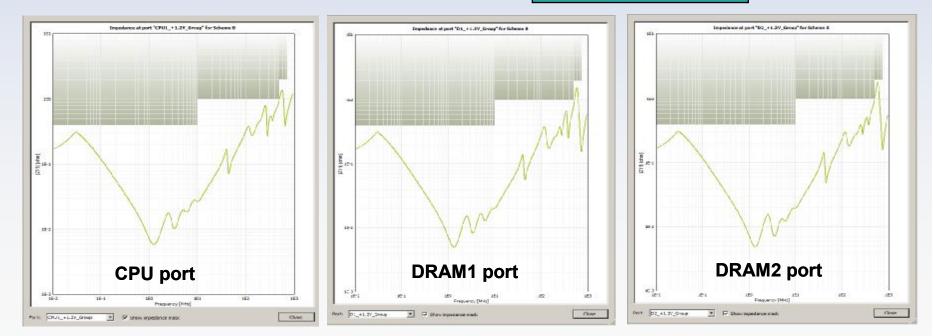
© 2010 ANSYS, Inc. All rights reserved.

Capacitor Count Reduction



Vame	Goodness of Fit	Price (\$)	Num Caps	Cap Types	1
cheme 8		0.11			
Scheme 7	0.999038	0.19	19	16	
Scheme 6	0.983764	0.11	11	11	
Scheme 5	0.975723	0.17	17	16	
Scheme 4	0.950819	0.18	18	15	
Scheme 3	0.949049	0.14	14	14	
Scheme 2	0.933681	0.1	10	10	
Scheme 1	0.933367	0.17	17	14	
Scheme 0	0.923817	0.16	16	13	





Apply Scheme 8 to Original Design ANSYS

Circuit Element Properties

Name	Goodness of Fit	Price (8)	Num Capis	Cap Types
Scheme 8	1	0.11	11	11
Scheme 7	0.999038	0.19	19	16
Schene 6	0.983764	0.11	81	11
Scheme 5	0.975723	0.17	17	16
Scheme 4	0.950819	0.18	10	15
Schene 3	0.949049	0.14	14	14
Schene 2	0.933681	0.1	13	10
Scheme 1	0.933367	0.17	17	14
Scheme 0	0.923817	0.16	15	13

Circuit Element Properties auto defined !

*	Active	8/8f	Part Number	RefDes	Capacitance (F)	Parasitic L (H)	Parasitic R (ohms)	Positive "Terminal" Net	Negative "Termina
1	Yes	×	GRM21BR	C19	2.2E-06	4.3452E-10	0.00438131	GND	+1.2V
1	Yes	×	GRM1885	C2	2.2E-10	7.82268E-10	0.139306	+1.2V	GND
1	Yes	×	GRM1885	C13	1.5E-10	7.93549E-10	0.170406	GND	+1.2V
1	Yes	×	GRM2195	C22	1.2E-08	4.94251E-10	0.0232748	+1.2V	GND -
1	Yes	×	GRM188R	C167	6.8E-10	5.07999E-10	0.386868	+1.2V	GND
1	Yes	×	GRM216R	C43	1E-06	2.84526E-10	0.0104462	+1.2V	GND
1	Yes	×	GRM188R	C17	1.2E-09	4.98611E-10	0.253293	+1.2V	GND
1	Yes	×	GRM216F	C170	1E-09	4.96929E-10	0.293964	+1.2V	GND
?	Yes	×	GRM188R	C52	2.7E-10	5.51632E-10	0.813567	+1.2V	GND
2	Yes	×	GRM188R	C47	2.2E-07	5.64599E-10	0.0252773	+1.2V	GND
-	Yes	×	GRM21BR	C180	2.2E-05	2.28044E-10	0.00232623	+1.2V	GND
2	No	×	GRM1885	C3	1.6E-10	7.90936E-10	0.15001	+1.2V	GND
2	No	×	GRM21BF	C4	2.2E-06	3.4867E-10	0.00433996	+1.2V	GND
?	No	×	GRM188R	C5	3.9E-10	5.38865E-10	0.59068	+1.2V	GND
?	No	×	GRM21BR	C6	2.2E-05	2.28044E-10	0.00232623	+1.2V	GND
2	No	×	GRM21BF	C7	2.2E-06	3.4867E-10	0.00433996	+1.2V	GND
2	No	×	GRM21BF	C8	2.2E-06	3.4867E-10	0.00433996	+1.2V	GND
?	No	×	GRM21BF	C9	2.2E-06	3.4867E-10	0.00433996	+1.2V	GND
2	No	×	GRM216R	C11	1E-06	2.64868E-10	0.0105327	GND	+1.2V
2	No	×	GRM21BR	C12	1E-07	5.00196E-10	0.0194763	GND	+1.2V
2	No	×	GRM21BF	C14	2.2E-06	3.4867E-10	0.00433996	+1.2V	GND
2	No	×	GRM2165	C15	1.6E-09	5.81412E-10	0.063323	+1.2V	GND
?	No	×	GRM188R	C16	4.7E-07	5.35164E-10	0.00913529	+1.2V	GND
1		×		C16				+1.2V	0.553.3578

х

Capacitors | Industry | Pasistern | Parts | Voltage Bashas | Current Sources | Voltage So

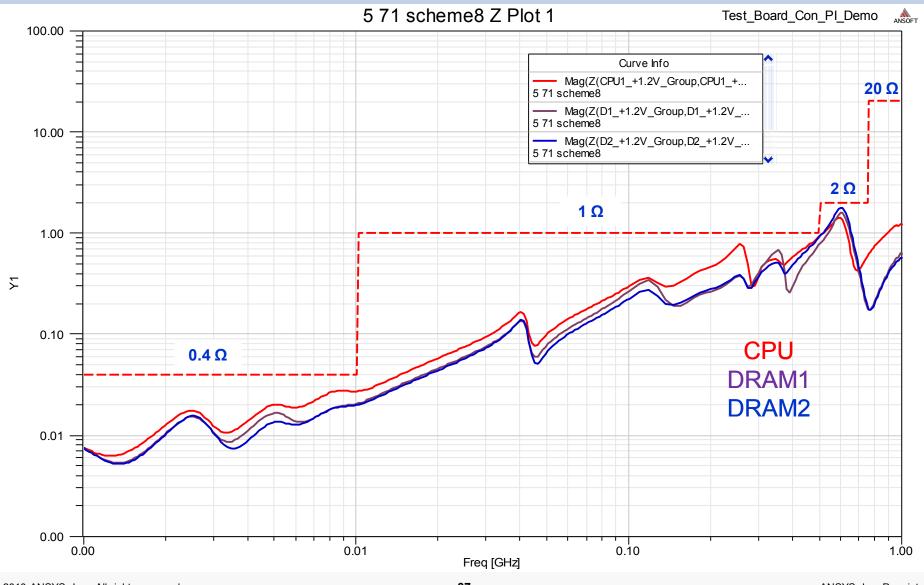
Re- Compute S,Y,Z parameters

ANSYS[®]

Image: Single Ended Nets Image: Single	Compute Resonant						
Image: Single Ended Nets Image: Single E	Compute Resonant						
Image: Single Ended Nets Image: Single							
Single Ended Nets 🗢 🕂 🗙 Differential		Modes	m				
	5 Compute Frequence	cy Sweep					
	Compute S-, Y-, Z-	parameters					
Regular Exp:	xp: Compute Far Fiel	ompute SYZ-p	oarameters				×
+1.2V +1.8V +1.8V_BST +1.8V_BSTRC +1.8V_FB	Dr Compute Near Fi Compute DC Cur SIvrizard (Design	Sweep Sensit	ivity	SYZ Sweep 1		•	
+1.8V_HG +1.8V_HGR	PI Advisor	Frequ	uency Range Set	up			
T+1RVIG			Start Freq / Hz	Stop Freq / Hz	Num. Points	Distribution	
		1	1E+06	1E+08	101	By Decade	
		2	1E+08	1E+09	101	Linear	
			d Above 📔 Add	I Below Dele	ete Selection		
		HG	a Above Add		ce pelection	Preview	
					Rise/Fall Time	on parameters e / s	

Final Simulation Results



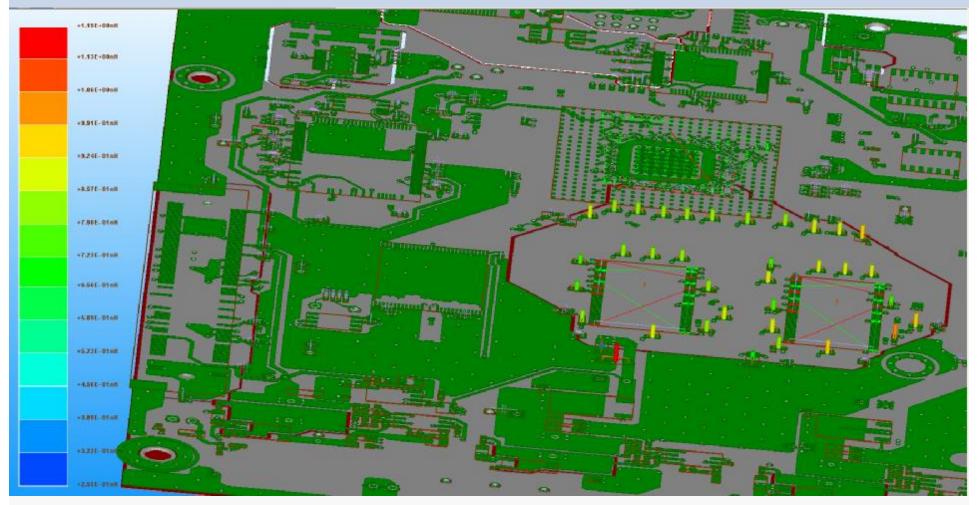


© 2010 ANSYS, Inc. All rights reserved.

Loop Inductance Plot



 Provides intuitive plot to analyze capacitor layout thereby minimizing loop inductance (all 36 caps displayed)



Efficient Simulation = Design Productivity **ANSYS**

^{*}2005 ITRS: "Cost of design is the greatest threat to the continuation of the semiconductor roadmap... [and] design productivity... is the most massive and critical [design challenge facing the industry today]."

*Source: International Technology Roadmap for Semiconductors

Delivering productivity:

Assume 4 to 5 changes per board

- Single PI Advisor simulation time ~ 3 min
- Simulation time is approximately 10-15 min.

Result: Your design team meets project performance requirements on time and, therefore, within budget.

Summary



- Achieving Adaptive Target Impedance Specifications is critical for overall system performance
- The advantages of *PI Advisor* were shown here.
 - Increase capacitor count in order to make design more robust
 - Reduce the capacitor count
 - Reduce number of different capacitor types used
 - Redesign using lower cost capacitors
- Efficient Power Integrity PCB Capacitor Optimization analysis and *"What-if..."* type analysis is utilized using:
 - Slwave
 - DesignerSI